

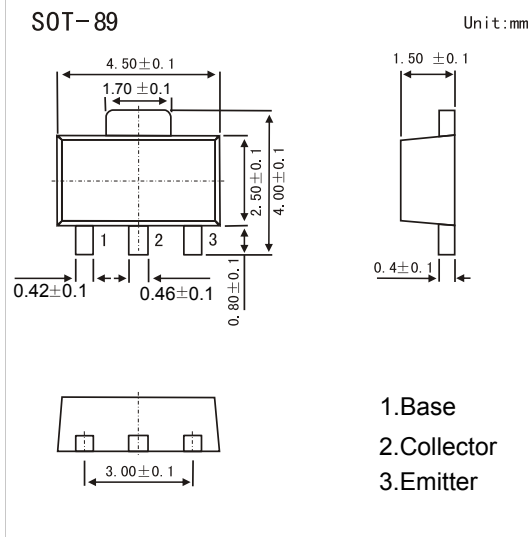
SOT-89 Plastic-Encapsulate Transistors

Features

- High breakdown voltage, $BV_{CEO} = -80V$, and High Current, $I_C = -0.7A$
- Complementary to 2SD1767
- PNP Transistors

MECHANICAL DATA

- Case style: SOT-89 molded plastic
- Mounting position: any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CB0}	-80	V
Collector - Emitter Voltage	V_{CE0}	-80	
Emitter - Base Voltage	V_{EB0}	-5	
Collector Current - Continuous	I_C	-0.7	A
Collector Power Dissipation	P_C	0.5	W
		2	
Junction Temperature	T_J	150	°C
Storage Temperature range	T_{stg}	-55 to 150	

PACKAGE INFORMATION

Device	Package	Shipping
2SB1189	SOT-89	1000/Tape&Reel

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V_{CB0}	$I_C = -100 \mu A, I_E = 0$	-80			V
Collector-emitter breakdown voltage	V_{CE0}	$I_C = -2 mA, I_B = 0$	-80			
Emitter-base breakdown voltage	V_{EB0}	$I_E = -100 \mu A, I_C = 0$	-5			
Collector-base cut-off current	I_{CB0}	$V_{CB} = -60V, I_E = 0$			-0.5	uA
Emitter cut-off current	I_{EB0}	$V_{EB} = -4V, I_C = 0$			-0.5	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -500 mA, I_B = -50mA$		-0.2	-0.4	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -500 mA, I_B = -50mA$			-1.2	
DC current gain	h_{FE}	$V_{CE} = -3V, I_C = -100 mA$	120		390	
Collector output capacitance	C_{ob}	$V_{CB} = -10V, I_E = 0, f = 1MHz$		14	20	pF
Transition frequency	f_T	$V_{CE} = -5V, I_E = 50mA, f = 100MHz$		100		MHz

Classification of hfe

Type	2SB1189-Q	2SB1189-R
Range	120-270	180-390
Marking	BD Q*	BD R*

RATINGS AND CHARACTERISTIC CURVES

■ Typical Characteristics

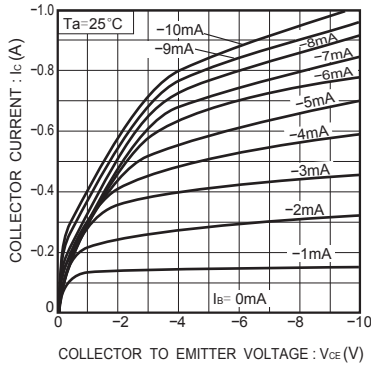


Fig.1 Ground emitter output characteristics

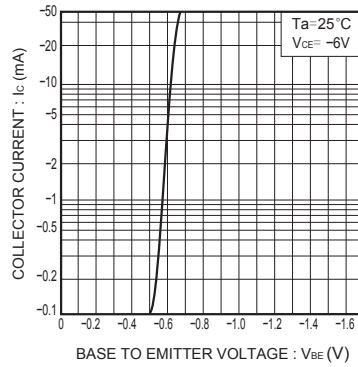


Fig.2 Ground emitter propagation characteristics

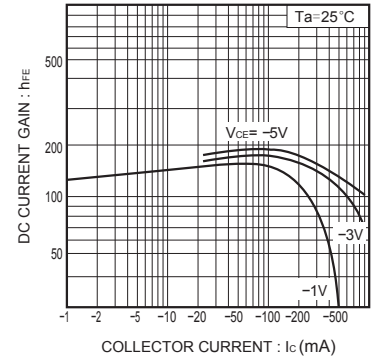


Fig.3 DC current gain vs. collector current

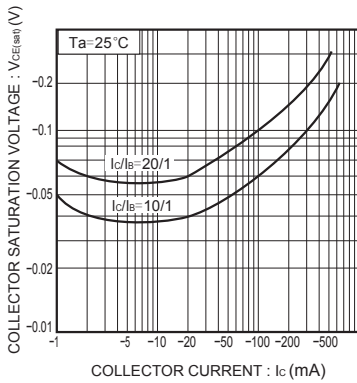


Fig.4 Collector-emitter saturation voltage vs. collector current

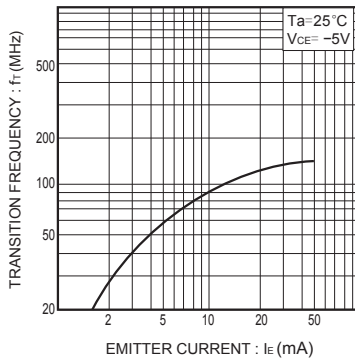


Fig.5 Gain bandwidth product vs. emitter current

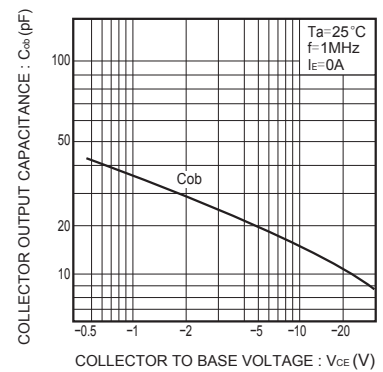


Fig.6 Collector output capacitance vs. collector-base voltage

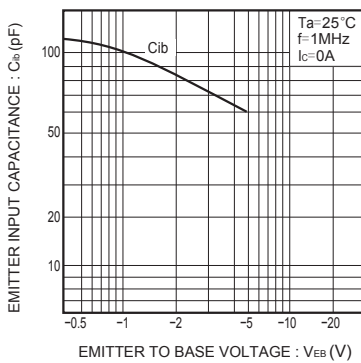


Fig.7 Emitter input capacitance vs. emitter-base voltage

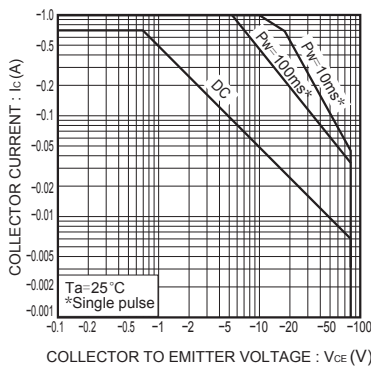


Fig.8 Safe operating area (2SB1189)